

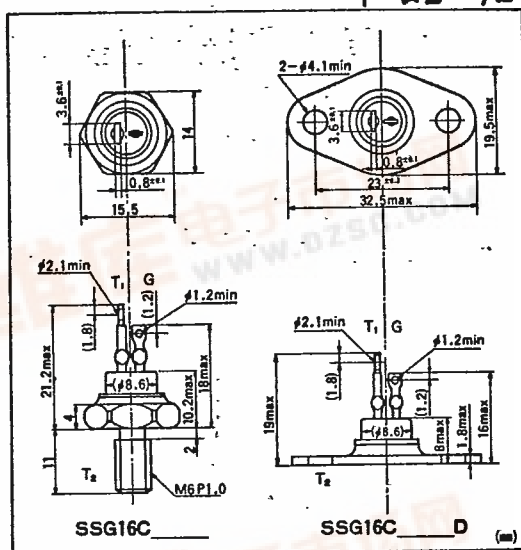
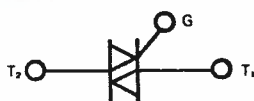
TRIAC

SSG16C

T104

For general A.C. power control applications such as A.C. switches, light controls, speed controls and heater controls etc.

- General A.C. power use
- $I_{T(RMS)}=16A$
- High voltage up to 1200V
- High surge current of 160A
- Package types; stud and diamond



Maximum Ratings

Item	Symbol	Unit	SSG16C 20(D)	SSG16C 30(D)	SSG16C 40(D)	SSG16C 50(D)	SSG16C 60(D)	SSG16C 80(D)	SSG16C 100(D)	SSG16C 120(D)
Repetitive Peak Off-State Voltage	V_{DRM}	V	200	300	400	500	600	800	1000	1200

Item	Symbol	Unit	Rating	Reference
RMS On-State Current	$I_{T(RMS)}$	A	16	$T_c=96^\circ C$
Surge On-State Current	I_{TSM}	A	140/160	One cycle 50/60Hz, peak, non-repetitive
I^2t (for fusing)	I^2t	A^2S	106	1 cycle
Peak Gate Power Dissipation	P_{GM}	W	10	
Average Gate Power Dissipation	$P_{G(AV)}$	W	1	
Peak Gate Current	I_{GM}	A	3	
Peak Gate Voltage	V_{GM}	V	10	
Critical Rate of Rise of On-State Current	di/dt	$A/\mu s$	50	$I_c=100mA$ $T_j=25^\circ C$ $V_D=\frac{1}{2}V_{DRM}$ $di_c/dt=1A/\mu s$
Operating Junction Temperature	T_j	$^\circ C$	-30~+125	
Storage Temperature	T_{stg}	$^\circ C$	-30~+125	
Mounting Torque		$kgf \cdot cm$	15	Recommended 12 $kgf \cdot cm$
Mass		g	11.0 (D type) 8.3	Excluding nut & washer. 2.6g. and wrapping material 0.1g

Electrical Characteristics

Item	Symbol	Unit	Rating	Reference
Repetitive Peak Off-State Current, max.	I_{DRM}	mA	3	at V_{DRM} , Single phase, half wave
Peak On-State Voltage, max.	V_{TM}	V	1.7	$I_T=25A$ $T_j=25^\circ C$ Inst. measurement
Gate Trigger Current, max.	1 I_{GT1}	mA	50	$T_j=25^\circ C$ $I_T=1A$ $V_D=6V$
	2 I_{GT1}	mA	50	$T_j=25^\circ C$ $I_T=1A$ $V_D=6V$
	3 I_{GT3}	mA	—	
	4 I_{GT3}	mA	50	$T_j=25^\circ C$ $I_T=1A$ $V_D=6V$
Gate Trigger Voltage, max.	1 V_{GT1}	V	3	$T_j=25^\circ C$ $I_T=1A$ $V_D=6V$
	2 V_{GT1}	V	3	$T_j=25^\circ C$ $I_T=1A$ $V_D=6V$
	3 V_{GT3}	V	—	
	4 V_{GT3}	V	3	$T_j=25^\circ C$ $I_T=1A$ $V_D=6V$
Non-Trigger Gate Voltage, min.	V_{GD}	V	0.2	$T_j=125^\circ C$ $V_D=\frac{1}{2}V_{DRM}$
Turn On Time, max.	t_{gt}	μs	10	$I_T=16A$ $I_c=100mA$ $V_D=\frac{1}{2}V_{DRM}$ $T_j=25^\circ C$ $di_c/dt=1A/\mu s$
Critical Rate of Rise of Off-State Voltage, min.	dv/dt	$V/\mu s$	50	$T_j=125^\circ C$, $V_D=\frac{2}{3}V_{DRM}$ Exponential wave.
Critical Rate of Rise of Off-State Voltage at Commutation, min.	$(dv/dt)_c$	$V/\mu s$	6	$T_j=125^\circ C$, $(di/dt)_c=8A/ms$, $V_D=\frac{2}{3}V_{DRM}$
Holding Current, typ.	I_H	mA	30	$T_j=25^\circ C$

T-25-15

